NSN 5961-01-327-8332

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-327-8332 **Inclosure Material:** Glass **Overall Length:** 0.102 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.062 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-34 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 repetitive peak reverse voltage and 60.0 reverse voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current preset **Capacitance Rating In Picofarads:** 1.6 **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: